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 Filing Date: 2-25-02
 First Named Inventor: James D. Beasom
 Group Art Unit: 2812
 Examiner Name: _____
 Attorney Docket: INT-0009A

FORM PTO-1449 COMMERCE		U.S. DEPARTMENT OF PATENT AND TRADEMARK OFFICE						
INFORMATION DISCLOSURE STATEMENT BY APPLICANT								
U.S. Patent Documents								
Examiner Initials	Cite No.	U.S. Patent Number	Kind Code	Name of Patentee or Applicant of Cited Document	Date of Publication	Pages, Columns, Lines Where Relevant Passages or Figures Appear		
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Other Prior Art - Non Patent Literature Documents								
Examiner Initials	Cite No	Name of Author (All Caps), Title of Article/Item, Date, Page(s), Volume-Issue Number(s), Publisher, City and/or Country Where Published					T	
MR	—	Sze, S.M. "Semiconductor Devices, Physics and Technology" John Wiley & Sons, Pg 384					—	
Examiner Signature	<i>MR</i>					Date Considered	TEC/11/04 03/09/04	RECEIVED MARCH 31 2002 U.S. PATENT & TRADEMARK OFFICE

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U.S. Patent Documents

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Examiner Signature	Date Considered
	03/09/04

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